## SN74ALVCH162344 1-BIT TO 4-BIT ADDRESS DRIVER WITH 3-STATE OUTPUTS

56 OE4

55 8B1

54 8B2

53 | GND

52 8B3

51 8B4

50 V<sub>CC</sub>

49 🛮 8A

48 🛮 7B1

47 🛮 7B2

46 GND

45 **7**B3

44 7B4

43 TA

42 6A

41 **∏** 6B1

40 6B2

39 **∏** GND

38 6B3 37 6B4

36 🛮 5A

35 V<sub>CC</sub>

34 5B1

33 5B2

32 GND

31 5B3

30 5B4

29 OE3

DGG, DGV, OR DL PACKAGE

(TOP VIEW)

OE1 [

1B1 **2** 

1B2 🛮 3

GND ∏4

1B3 🛮 5

1B4 **[**] 6

V<sub>CC</sub> [] 7

2B1 🛮 9

2B2 10

GND 11

2B3 🛮 12

2B4 🛮 13

2A **∏** 14

3A **∏** 15

3B1 **1**16

3B2 🛮 17

GND ∏18

3B3 **1** 19

3B4 **1**20

4A 🛮 21

V<sub>CC</sub> [ 22 4B1 [ 23

4B2 **2**4

GND [] 25

4B3 **1**26

4B4 **∏** 27

OE2 28

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- Member of the Texas Instruments Widebus™ Family
- EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process
- Output Ports Have Equivalent 26-Ω Series Resistors, So No External Resistors Are Required
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic 300-mil Shrink Small-Outline (DGG), Thin Shrink Small-Outline (DL), and Thin Very Small-Outline (DGV) Packages

NOTE: For tape and reel order entry:

The DGGR package is abbreviated to GR, and the DGVR package is abbreviated to VR.

### description

This 1-bit to 4-bit address driver is designed for 1.65-V to 3.6-V  $V_{CC}$  operation.

The SN74ALVCH162344 is used in applications in which four separate memory locations must be addressed by a single address.

The outputs, which are designed to sink up to 12 mA, include equivalent 26- $\Omega$  resistors to reduce overshoot and undershoot.

To ensure the high-impedance state during power up or power down, the output enable  $(\overline{OE})$  inputs should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74ALVCH162344 is characterized for operation from -40°C to 85°C.

#### **A-TO-B FUNCTION TABLE**

INPU	JTS	OUTPUT		
OE	Α	Bn		
L	Н	Н		
L	L	L		
Н	Χ	Z		



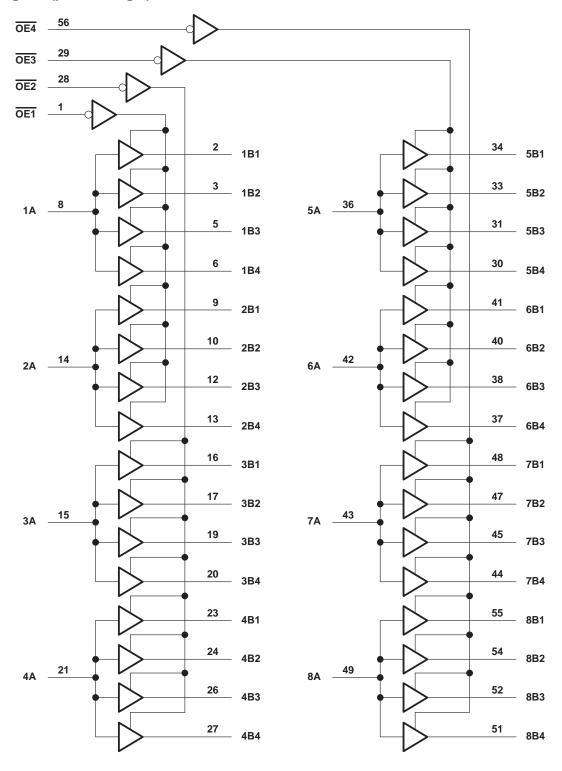
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TEXAS INSTRUMENTS

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### logic diagram (positive logic)





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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	
Input voltage range, V <sub>I</sub> (see Note 1)	
Output voltage range, VO (see Notes 1 and 2)	
Input clamp current, $I_{ K }(V_{ C } < 0)$	–50 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	–50 mA
Continuous output current, IO	±50 mA
Continuous current through each V <sub>CC</sub> or GND	±100 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 3): DGG package	ige 81°C/W
DGV packa	ge 86°C/W
DL package	9
Storage temperature range, T <sub>stq</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. This value is limited to 4.6 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51.

### recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
VCC	Supply voltage		1.65	3.6	V	
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>			
$V_{IH}$	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2			
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		0.35 × V <sub>CC</sub>	V	
$V_{IL}$		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7		
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		
٧ <sub>I</sub>	Input voltage		0	Vcc	V	
٧o	Output voltage		0	Vcc	V	
ЮН		V <sub>CC</sub> = 1.65 V		-2		
	High-level output current	V <sub>CC</sub> = 2.3 V		-6	mA	
		V <sub>CC</sub> = 2.7 V		-8		
		V <sub>CC</sub> = 3 V		-12		
		V <sub>CC</sub> = 1.65 V		2		
la.	Low-level output current	V <sub>CC</sub> = 2.3 V		6	A	
IOL		V <sub>CC</sub> = 2.7 V		8	mA	
	V <sub>CC</sub> = 3 V			12		
Δt/Δν	Input transition rise or fall rate			10	ns/V	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

NOTE 4: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



# SN74ALVCH162344 1-BIT TO 4-BIT ADDRESS DRIVER WITH 3-STATE OUTPUTS

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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PAI	RAMETER	TEST CONDITIONS	Vcc	MIN	TYP <sup>†</sup>	MAX	UNIT	
		$I_{OH} = -100 \mu\text{A}$	1.65 V to 3.6 V	V <sub>CC</sub> -0.	2			
		$I_{OH} = -2 \text{ mA}$	1.65 V	1.2				
		$I_{OH} = -4 \text{ mA}$	2.3 V	1.9				
Vон		Ja 6 m/s	2.3 V	1.7			V	
		I <sub>OH</sub> = -6 mA	3 V	2.4				
		$I_{OH} = -8 \text{ mA}$	2.7 V	2				
		$I_{OH} = -12 \text{ mA}$	3 V	2				
		$I_{OL} = 100 \mu\text{A}$	1.65 V to 3.6 V			0.2		
		$I_{OL} = 2 \text{ mA}$	1.65 V			0.45		
		I <sub>OL</sub> = 4 mA	2.3 V			0.4		
VOL		lo 6 mA	2.3 V			0.55	V	
		I <sub>OL</sub> = 6 mA	3 V			0.55		
		$I_{OL} = 8 \text{ mA}$	2.7 V			0.6		
		$I_{OL} = 12 \text{ mA}$	3 V			0.8		
lį		$V_I = V_{CC}$ or GND	3.6 V			±5	μΑ	
		$V_{I} = 0.58 \text{ V}$	1.65 V	25				
		V <sub>I</sub> = 1.07 V	1.65 V	-25			μΑ	
		$V_I = 0.7 V$	2.3 V	45				
I <sub>I</sub> (hold)		V <sub>I</sub> = 1.7 V	2.3 V	-45				
		V <sub>I</sub> = 0.8 V	3 V	75				
		V <sub>I</sub> = 2 V	3 V	-75				
		$V_{I} = 0 \text{ to } 3.6 \text{ V}^{\ddagger}$	3.6 V			±500		
loz		$V_O = V_{CC}$ or GND	3.6 V			±10	μΑ	
ICC		$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V			40	μΑ	
∆lcc		One input at $V_{CC}$ – 0.6 V, Other inputs at $V_{CC}$	/ <sub>CC</sub> or GND 3 V to 3.6 V			750	μΑ	
C:	Control inputs	Vi – Voo or GND	3.3 V		2.5		p.E	
Ci	Data inputs	$V_I = V_{CC}$ or GND	3.3 V		3.5		pF	
Со	Outputs	$V_O = V_{CC}$ or GND	3.3 V		4		pF	

 $<sup>\</sup>dagger$  All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.

# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

ſ	PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> =	V <sub>CC</sub> = 2.5 V ± 0.2 V		C = 2.5 V 0.2 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V	
l		(INFOT)	(0011-01)	TYP	MIN	MAX	MIN	MAX	MIN	MAX			
Γ	<sup>t</sup> pd	А	В	§	1	4.9		5.1	1.4	4.4	ns		
Γ	<sup>t</sup> en	ŌĒ	В	§	1	6.4		6.6	1.2	5.7	ns		
Γ	t <sub>dis</sub>	ŌE	В	§	1	5.4		4.7	1.2	4.5	ns		
	t <sub>sk(o)</sub> ¶									0.35	ns		
Γ	tsk(o)#									0.5	ns		

<sup>§</sup> This information was not available at the time of publication.

<sup>#</sup> Skew between outputs of all banks of same package (A1–A8 tied together)



<sup>‡</sup> This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

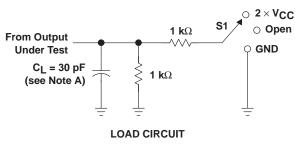
 $<sup>\</sup>P$  Skew between outputs of the same bank and same package (same transition)

### operating characteristics, T<sub>A</sub> = 25°C

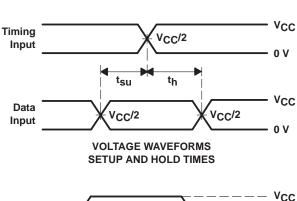
PARAMETER			TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	UNIT	
	PARAMETER		TEST CONDITIONS	TYP	TYP	TYP	ONII	
	Power dissipation	Outputs enabled	$C_1 = 0$ , $f = 10 \text{ MHz}$	†	68	82	pF	
Cpd	capacitance	Outputs disabled	$C_L = 0$ , $f = 10 \text{ MHz}$	†	12	14	pr	

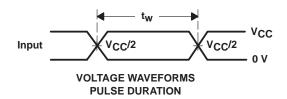
<sup>†</sup> This information was not available at the time of publication.

### PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 V$



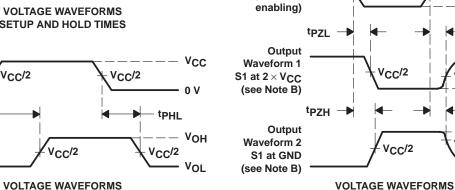






V<sub>CC</sub>/2

**ENABLE AND DISABLE TIMES** 



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{O} = 50 \Omega$ ,  $t_{f} \leq$  2 ns,  $t_{f} \leq$  2 ns.

Output

Control

(low-level

- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.

**PROPAGATION DELAY TIMES** 

Input

Output

tPLH :

- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



VCC

– 0 V

VCC

VoL

— V<sub>ОН</sub>

- 0 V

V<sub>CC</sub>/2

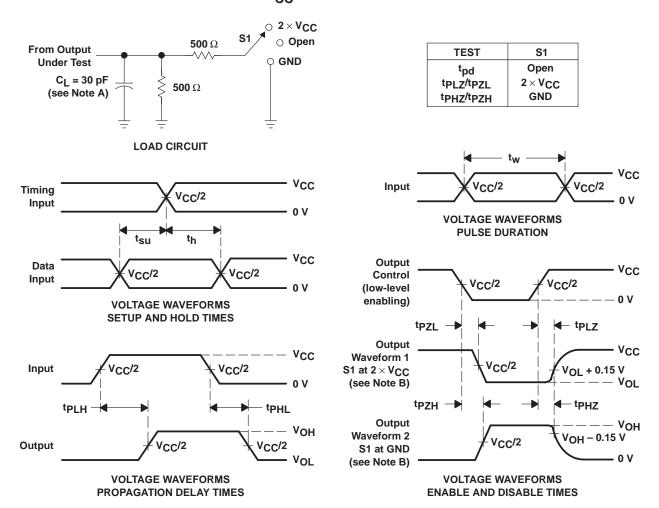
- tpi 7

V<sub>OL</sub> + 0.15 V

V<sub>OH</sub> – 0.15 V

- tPHZ

### PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 V \pm 0.2 V$



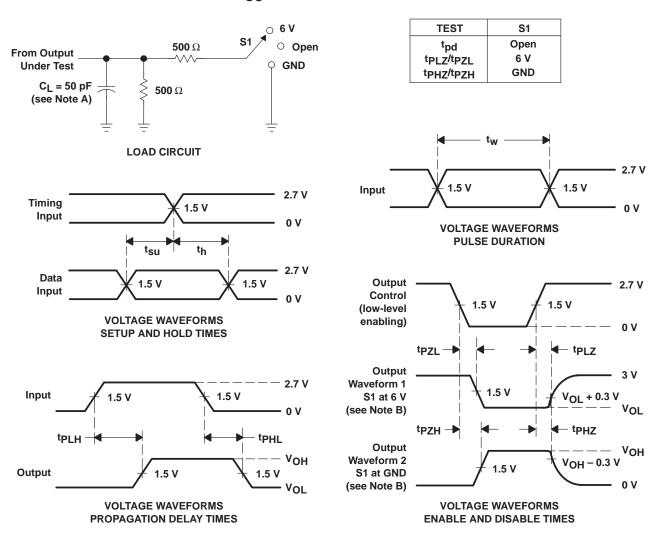
- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq$  2 ns.  $t_f \leq$  2 ns.
  - D. The outputs are measured one at a time with one transition per measurement.
  - E. tpLZ and tpHZ are the same as tdis.
  - F. tpzL and tpzH are the same as ten.
  - G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



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### PARAMETER MEASUREMENT INFORMATION $V_{CC}$ = 2.7 V AND 3.3 V $\pm$ 0.3 V



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_Q = 50 \Omega$ ,  $t_{\Gamma} \leq$  2.5 ns,  $t_{\Gamma} \leq$  2.5 ns.
  - D. The outputs are measured one at a time with one transition per measurement.
  - E. tpl 7 and tpH7 are the same as tdis-
  - F. tpzL and tpzH are the same as ten.
  - G. tpLH and tpHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms

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